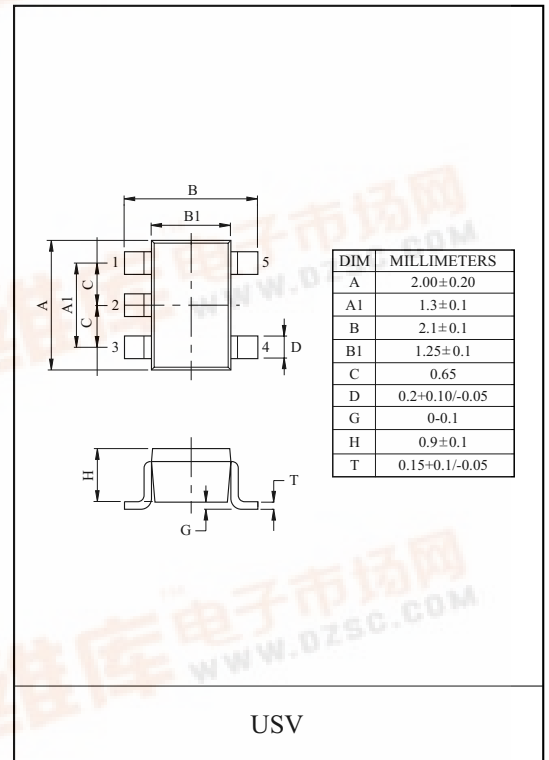


2 INPUT OR GATE

FEATURES

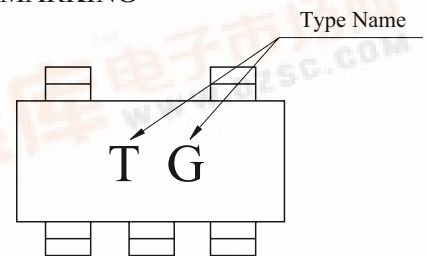
- High Output Drive : $\pm 24\text{mA}$ (Typ.) @ $V_{CC}=3\text{V}$
- Super High Speed Operation : $t_{PD}=2.4\text{ns}$ (Typ.) @ $V_{CC}=5\text{V}$, 50pF
- Operation Voltage Range : $V_{CC(\text{opr})}=1.8 \sim 5.5\text{V}$.
- Supply Voltage Data Retention : $V_{CC}=1.5 \sim 5.5\text{V}$.
- 5V Tolerant Function



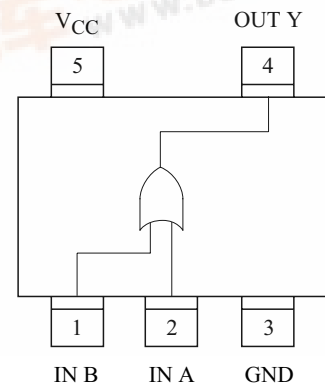
MAXIMUM RATINGS (Ta=25 °C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	-0.5 ~ 6	V
DC Input Voltage	V_{IN}	-0.5 ~ 6	V
DC Output Voltage	V_{OUT}	-0.5 ~ 6	V
Input Diode Current	I_{IK}	±20	mA
Output Diode Current	I_{OK}	±20	mA
DC Output Current	I_{OUT}	±50	mA
DC V_{CC} /Ground Current	I_{CC}	±50	mA
Power Dissipation	P_D	200	mW
Storage Temperature	T_{stg}	-65 ~ 150	°C
Lead Temperature (10s)	T_L	260	°C

MARKING

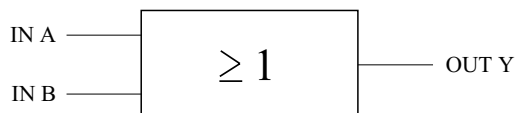


PIN CONNECTION (TOP VIEW)



KIC7SZ32FU

LOGIC DIAGRAM



DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION	V _{CC} (V)	Ta=25 °C			Ta=-40 ~85 °C		UNIT	
				MIN.	TYP.	MAX.	MIN.	MAX.		
High-Level Input Voltage	V _{IH}	-	1.8	0.88 ×V _{CC}	-	-	0.88 ×V _{CC}	-	V	
			2.3 ~ 5.5	0.75 ×V _{CC}	-	-	0.75 ×V _{CC}	-		
Low-Level Input Voltage	V _{IL}	-	1.8	-	-	0.12 ×V _{CC}	-	0.12 ×V _{CC}	V	
			2.3 ~ 5.5	-	-	0.25 ×V _{CC}	-	0.25 ×V _{CC}		
High-Level Output Voltage	V _{OH}	V _{IN} =V _{IH} or V _{IL}	I _{OH} =-100μA	1.8	1.7	1.8	-	1.7	-	V
				2.3	2.2	2.3	-	2.2	-	
				3.0	2.9	3.0	-	2.9	-	
				4.5	4.4	4.5	-	4.4	-	
			I _{OH} =-8mA	2.3	1.9	2.15	-	1.9	-	
			I _{OH} =-16mA	3.0	2.4	2.8	-	2.4	-	
			I _{OH} =-24mA	3.0	2.3	2.68	-	2.3	-	
Low-Level Output Voltage	V _{OL}	V _{IN} =V _{IH} or V _{IL}	I _{OL} =100μA	1.8	-	0	0.1	-	0.1	V
				2.3	-	0	0.1	-	0.1	
				3.0	-	0	0.1	-	0.1	
				4.5	-	0	0.1	-	0.1	
			I _{OL} =8mA	2.3	-	0.1	0.3	-	0.3	
			I _{OL} =16mA	3.0	-	0.15	0.4	-	0.4	
			I _{OL} =24mA	3.0	-	0.22	0.55	-	0.55	
Input Leakage Current	I _{IN}	V _{IN} =5.5V or GND	0 ~5.5	-	-	±1	-	±10	μA	
			Quiescent Supply Current	I _{CC}	V _{IN} =V _{CC} or GND	5.5	-	-		2

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AC ELECTRICAL CHARACTERISTICS (Input $t_r=t_f=3\text{ns}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	Ta=25 °C			Ta=-40 ~ 85 °C		UNIT	
			V _{CC} (V)	MIN.	TYP.	MAX.	MIN.		MAX.
Propagation Delay Time	t_{PLH} t_{PHL}	$C_L=15\text{pF}$, $R_L=1\text{M}\Omega$	1.8	2.0	4.6	10.0	2.0	10.5	ns
			2.5 ± 0.2	0.8	3.0	7.0	0.8	7.5	
			3.3 ± 0.3	0.5	2.4	4.7	0.5	5.0	
			5.0 ± 0.5	0.5	1.9	4.1	0.5	4.4	
		$C_L=50\text{pF}$, $R_L=500\Omega$	3.3 ± 0.3	1.5	3.0	5.2	1.5	5.5	
			5.0 ± 0.5	0.8	2.4	4.5	0.8	4.8	
Input Capacitance	C_{IN}	-	0~5.5	-	4	-	-	pF	
Power Dissipation Capacitance	C_{PD}	(Note1)	3.3	-	20	-	-		
			3.5	-	26	-	-		

Note 1 : C_{PD} defined as the value of internal equivalent capacitance of IC which is calculated from the operating current consumption without load (refer to Test Circuit.) Average operating current can be obtained by the equation hereunder.

$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

